



M.S.KENNEDY CORP.

1200V/150A THREE PHASE BRIDGE PEM WITH BRAKE

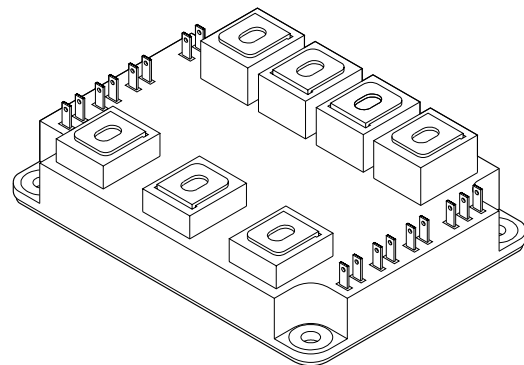
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FEATURES:

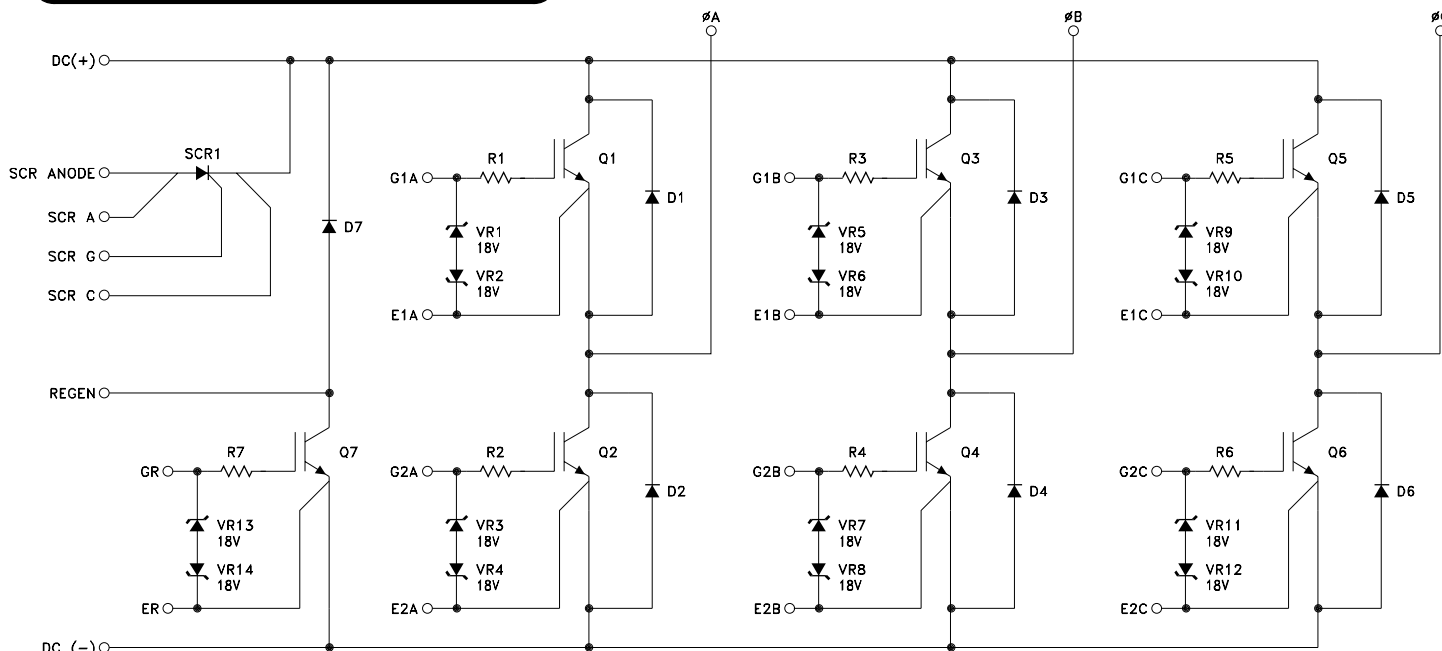
- Full Three Phase Bridge Configuration with SCR/IGBT Brake
- 1200V Rated Voltage
- 150A Continuous Output Current
- Internal Zener Clamps on Gates
- Proprietary Encapsulation Provides Near Hermetic Performance
- MIL-PRF-38534 Screening Available (Modified)
- Light Weight Domed ALSIC Baseplate
- Robust Mechanical Design for Hi-Rel Applications
- Ultra-Low Inductance Internal Layout
- Withstands 96 Hours HAST and Thermal Cycling (-55° C to + 125° C)
- Contact MSK for MIL-PRF-38534 Qualification Status



DESCRIPTION:

The MSK 4852 is one of a family of plastic encapsulated modules (PEM) developed specifically for use in military, aerospace and other severe environment applications. The Three Phase Bridge configuration along with the SCR/IGBT brake circuit and 1200 volt/150 amp rating make it ideal for use in high current motor drive and inverter applications. The Aluminum Silicon Carbide (AlSiC) baseplate offers superior flatness and light weight; far better than the copper or copper alloys found in most high power plastic modules. The high thermal conductivity materials used to construct the MSK 4852 allow high power outputs at elevated baseplate temperatures. Our proprietary coating, SEES™ - Severe Environment Encapsulation System - protects the internal circuitry of MSK PEM's from moisture and contamination, allowing them to pass the rugged environmental screening requirements of military and aerospace applications. MSK PEM's are also available with industry standard silicone gel coatings for a lower cost option.

EQUIVALENT SCHEMATIC



TYPICAL APPLICATIONS

- Motor Drives
- Inverters

ABSOLUTE MAXIMUM RATING ^⑩

<p>VCE Collector to Emitter Voltage 1200V</p> <p>VGE Gate to Emitter Voltage ± 20V</p> <p>IOUT Current (Continuous) 150A</p> <p>IOUTP Current Pulsed (1mS) 300A</p> <p>ISCR/REG Current (Continuous) 100A</p> <p>ISCR/REG Current Pulsed (1ms) 150A</p>	<p>VCASE Case Isolation Voltage 2500V</p> <p>TST Storage Temperature Range . . -55°C to + 125°C</p> <p>TJ Junction Temperature 150°C</p> <p>TC Case Operating Temperature Range</p> <p style="padding-left: 20px;">MSK 4852H/E -55°C to + 125°C</p> <p style="padding-left: 20px;">MSK 4852 -40°C to + 85°C</p>
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ELECTRICAL SPECIFICATIONS

Parameter ^⑥	Test Conditions	Group A Subgroup	MSK 4852 H/E			MSK 4852			Units
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Collector-Emitter Saturation Voltage ^⑧	IC = 150A, VGE = 15V	1	-	1.9	2.5	-	1.9	2.6	V
		2	-	2.3	2.9	-	2.3	3.0	V
		3	-	1.9	2.5	-	1.9	2.5	V
Collector-Emitter Saturation Voltage ^⑦	IC = 150A, VGE = 15V	1,3	-	1.7	-	-	1.7	-	V
		2	-	1.9	-	-	1.9	-	V
Collector-Emitter Leakage Current	VCE = 1000V, VGE = 0V	1	-	0.05	6	-	0.05	8	mA
		2	-	0.1	10	-	0.1	12	mA
		① 3	-	0.05	6	-	0.05	8	mA
Gate Threshold Voltage	IC = 6mA, VCE = VGE	1	4.0	5.8	6.5	4.0	5.8	6.6	V
		2	3.5	5.0	6.0	3.5	5.0	6.1	V
		3	4.0	5.9	6.6	4.0	5.9	6.7	V
Gate Leakage Current	VCE = 0V, VGE = ± 15V	1,3	-10	0.10	10	-12	0.10	12	µA
		2	-10	0.15	10	-12	0.15	12	µA
Diode Forward Voltage ^⑧	IC = 150A	1	-	1.8	2.4	-	1.8	2.5	V
		2	-	1.8	2.4	-	1.8	2.5	V
		3	-	1.7	2.4	-	1.7	2.5	V
Diode Forward Voltage ^⑦	IC = 150A	1,2	-	1.7	-	-	1.7	-	V
		3	-	1.6	-	-	1.6	-	V
SCR Reverse Leakage	VRRM = 1000V	1,2,3	-	0.01	10	-	0.01	12	mA
SCR On Voltage ^⑧	IF = 100A	1	-	1.1	1.35	-	1.1	1.4	V
		2	-	1.0	1.35	-	1.0	1.4	V
		3	-	1.2	1.5	-	1.2	1.6	V
SCR Holding Current		1	-	100	300	-	100	325	mA
		2	-	90	300	-	90	325	mA
		3	-	110	300	-	110	325	mA
Regen Diode Forward Voltage	IF = 50A	1	-	1.5	2.2	-	1.3	2.3	V
		2	-	1.5	2.2	-	1.5	2.3	V
		3	-	1.4	2.2	-	1.4	2.3	V
Total Gate Charge ^①	V = 600V, IC = 150A	4	-	1000	1500	-	1000	1600	nC
Turn-On Delay ^①	V = 600V, IC = 150A, RG = 20Ω	4	-	300	450	-	300	475	nS
Rise Time ^①	V = 600V, IC = 150A, RG = 20Ω	4	-	70	110	-	70	120	nS
E(on) ^①	V = 600V, IC = 150A, RG = 20Ω, VGE = -7/+ 15V	4	-	23	-	-	23	-	mJ
		5	-	31	-	-	31	-	mJ
E(off) ^①	V = 600V, IC = 150A, RG = 10Ω, VGE = -7/+ 15V	4	-	12	-	-	12	-	mJ
		5	-	17	-	-	17	-	mJ
Turn-Off Delay ^①	V = 600V, IC = 150A, RG = 10Ω	4	-	650	975	-	650	995	µS
Fall Time ^①	V = 600V, IC = 150A, RG = 10Ω	4	-	75	125	-	75	135	nS
Diode Reverse Recovery Time ^①	IE = 150A, di/dt = 1250A/µS	4	-	460	650	-	460	675	nS
Diode Reverse Recovery Charge ^①	IE = 150A, di/dt = 1250A/µS	4	-	13.4	20	-	13.4	25	µC
Thermal Resistance ^①	IGBT @ TJ = 125°C	4	-	0.16	0.2	-	0.16	0.21	°C/W
	BRIDGE DIODE @ TJ = 125°C	4	-	0.26	0.32	-	0.26	0.33	°C/W
	REGEN SCR	4	-	0.16	0.2	-	0.16	0.21	°C/W
	REGEN DIODE	4	-	0.35	0.43	-	0.35	0.44	°C/W

NOTES:

- ① Guaranteed by design but not tested. Typical parameters are representative of actual device performance but are for reference only.
- ② Industrial grade and "E" suffix devices shall be tested to subgroup 1 unless otherwise specified.
- ③ Military grade devices ("H" suffix) shall be 100% tested to subgroups 1, 2 and sample tested to subgroup 3.
- ④ Subgroups 4, 5 and 6 testing available upon request.
- ⑤ Subgroup 1, 4 TA = +25°C
2, 5 TA = +125°C
3, 6 TA = -55°C
- ⑥ All specifications apply to both the upper and lower sections of the half bridge.
- ⑦ Measurements are made by forcing current through the power lugs and measuring the actual die drop at the small signal terminals. Measurements are provided for determining thermal dissipation on the IGBT/diode.
- ⑧ Measurements includes die, substrate, wire bond and power lug.
- ⑨ VGE = 15V unless otherwise specified.
- ⑩ Continuous operation at or above absolute maximum ratings may adversely effect the device performance and/or life cycle.

THERMAL CALCULATIONS

Power dissipation and maximum allowable temperature rise involve many variables working together. Collector current, PWM duty cycle and switching frequency all factor into power dissipation. DC losses or "ON-TIME" losses are simply $V_{CE(SAT)} \times \text{Collector Current} \times \text{PWM duty cycle}$. For the MSK 4852, $V_{CE(SAT)} = 1.9V$ typically, and at 150 amps and a PWM duty cycle of 30%, DC losses equal 85.5 watts. Switching losses, in milli-joules, vary proportionally with switching frequency. The MSK 4852 typical switching losses at $V_{CE} = 600V$ and $I_{CE} = 150A$ are about 48mJ, which is simply the sum of the turn-on switching loss and the turn-off switching loss. Multiplying the switching frequency times the switching losses will result in a power dissipation number for switching. The MSK 4852, at 10KHz, will exhibit switching power dissipation of 480 watts. The total losses are the sum of DC losses plus switching losses, or in this case, 565.5 watts total.

565.5 watts x 0.20° C/W thermal resistance equals 113 degrees of temperature rise between the case and the junction. Subtracting 113° C from the maximum junction temperature of 150° C equals 37° C maximum case temperature for this example.

$$V_{CE(SAT)} \times I_C \times \text{PWM duty cycle} = 1.9V \times 150 \text{ amps} \times 30\% = 85.5 \text{ watts DC losses}$$

$$\text{Turn-on switching loss} + \text{Turn-off switching loss} = \text{Total switching losses} = 31 + 17 = 48\text{mJ}$$

$$\text{Total switching loss} \times \text{PWM frequency} = \text{Total switching power dissipation} = 48\text{mJ} \times 10\text{KHz} = 480\text{watts}$$

$$\text{Total power dissipation} = \text{DC losses} + \text{switching losses} = 85.5 + 480 = 565.5 \text{ watts}$$

$$\text{Junction temperature rise above case} = \text{Total power dissipation} \times \text{thermal resistance}$$

$$565.5 \text{ watts} \times 0.2^\circ \text{C/W} = 113^\circ \text{C temperature rise above case}$$

$$\text{Maximum junction temperature} - \text{junction temperature rise} = \text{maximum baseplate temperature}$$

$$150^\circ \text{C} - 113^\circ \text{C} = 37^\circ \text{C}$$

TYPICAL PERFORMANCE CURVES

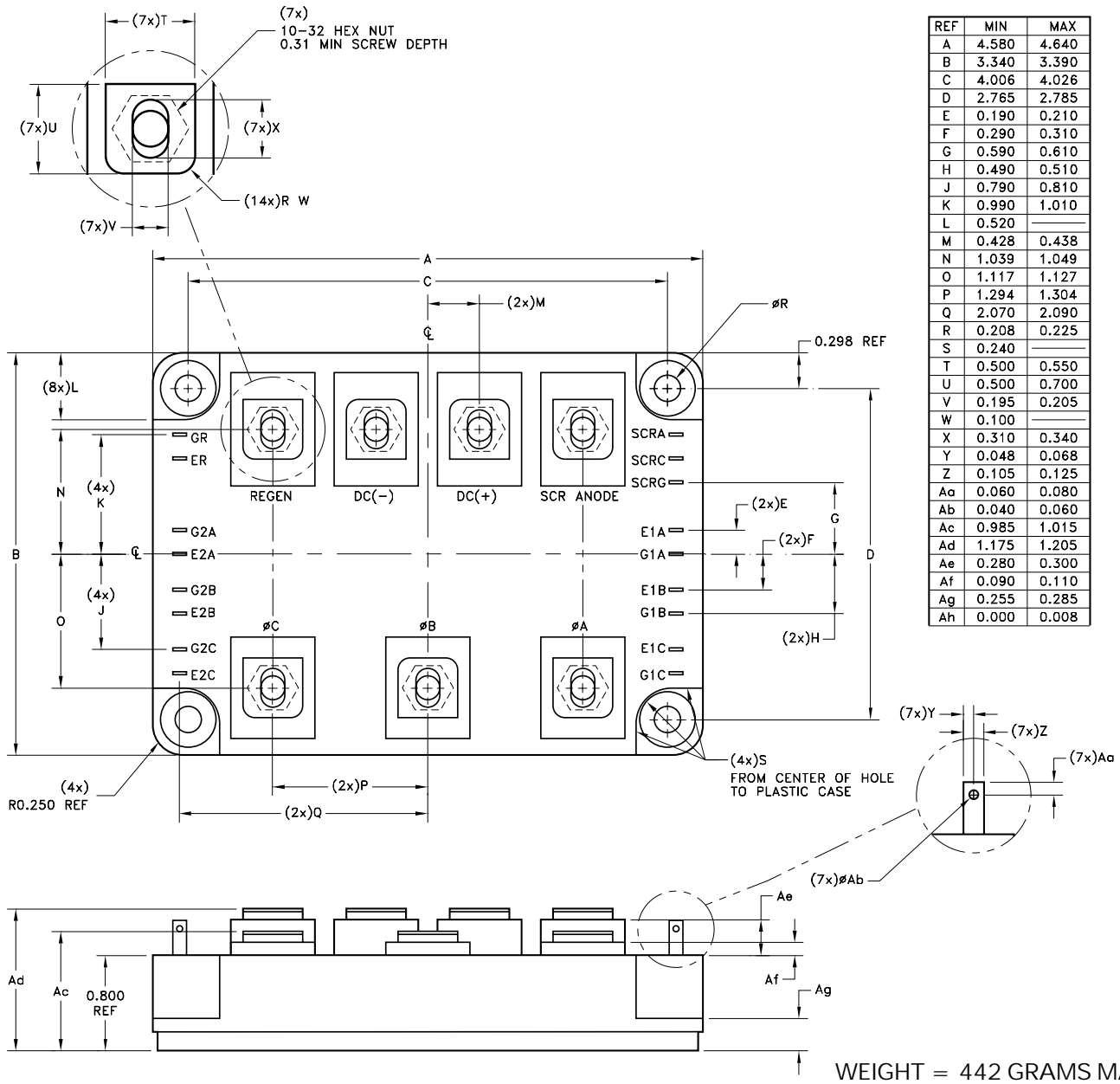
TBD

SCREENING CHART

OPERATION IN ACCORDANCE WITH MIL-PRF-38534	INDUSTRIAL	CLASS E	CLASS H
QUALIFICATION (MODIFIED)	NO	NO	YES
ELEMENT EVALUATION	NO	YES	YES
CLEAN ROOM PROCESSING	YES	YES	YES
NON DESTRUCT BOND PULL SAMPLE	YES	YES	YES
CERTIFIED OPERATORS	NO	YES	YES
MIL LINE PROCESSING	YES	YES	YES
MAX REWORK SPECIFIED	NO	YES	YES
ENCAPSULANT	GEL COAT	SEES™	SEES™
PRE-CAP VISUAL	YES - INDUSTRIAL	YES - CLASS H	YES - CLASS H
TEMP CYCLE (-55°C TO +125°C)	NO	YES	YES
BURN-IN	NO	YES - 96 HOURS	YES - 160 HOURS
ELECTRICAL TESTING	YES - 25°C	YES - 25°C	YES - FULL TEMP
EXTERNAL VISUAL	YES - SAMPLE	YES - SAMPLE	YES
XRAY	NO	NO	NO
PIN FINISH	NI	NI	NI

NOTE: ADDITIONAL SCREENING IS AVAILABLE SUCH AS XRAY, CSAM, MECHANICAL SHOCK, ETC. CONTACT FACTORY FOR QUAL STATUS.

MECHANICAL SPECIFICATIONS



ORDERING INFORMATION

MSK4852 H

SCREENING

BLANK = INDUSTRIAL; E = EXTENDED RELIABILITY;
 H = MIL-PRF-38534 CLASS H (MODIFIED)

GENERAL PART NUMBER

THE ABOVE EXAMPLE IS A MILITARY SCREENED MODULE.

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Please visit our website for the most recent revision of this datasheet.

Contact MSK for MIL-PRF-38534 qualification status.